SMBJ5.0A thru SMBJ188A

Vishay General Semiconductor

RoHS

COMPLIANT

Surface Mount TRANSZORB[®] Transient Voltage Suppressors



DO-214AA (SMB J-Bend)

PRIMARY CHARACTERISTICS					
V _{BR} (bi-directional)	6.4 V to 231 V				
V _{BR} (uni-directional)	6.4 V to 231 V				
V _{WM}	5.0 V to 188 V				
P _{PPM}	600 W				
I _{FSM} (uni-directional only)	100 A				
T _J max.	150 °C				
Polarity	Uni-directional, bi-directional				
Package	DO-214AA (SMBJ)				

DEVICES FOR BI-DIRECTION APPLICATIONS

For bi-directional devices use CA suffix (e.g. SMBJ10CA). Electrical characteristics apply in both directions.

FEATURES

- Low profile package
- Ideal for automated placement
- Glass passivated chip junction
- Available in uni-directional and bi-directional
- 600 W peak pulse power capability with a 10/1000 μs waveform, repetitive rate (duty cycle): 0.01 %
- Excellent clamping capability
- Very fast response time
- Low incremental surge resistance
- Meets MSL level 1, per J-STD-020, LF maximum peak of 260 °C
- AEC-Q101 qualified
- Material categorization: For definitions of compliance please see <u>www.vishay.com/doc?99912</u>

TYPICAL APPLICATIONS

Use in sensitive electronics protection against voltage transients induced by inductive load switching and lighting on ICs, MOSFET, signal lines of sensor units for consumer, computer, industrial, and telecommunication.

MECHANICAL DATA

Case: DO-214AA (SMBJ)

Molding compound meets UL 94 V-0 flammability rating Base P/N-E3 - RoHS-compliant, commercial grade Base P/NHE3 - RoHS-compliant, AEC-Q101 qualified

Terminals: Matte tin plated leads, solderable per J-STD-002 and JESD 22-B102

E3 suffix meets JESD 201 class 1A whisker test, HE3 suffix meets JESD 201 class 2 whisker test

Polarity: For uni-directional types the band denotes cathode end, no marking on bi-directional types

MAXIMUM RATINGS (T _A = 25 °C unless otherwise noted)							
PARAMETER	SYMBOL	VALUE	UNIT				
Peak pulse power dissipation with a 10/1000 μs waveform $^{(1)(2)}$ (fig. 1)	P _{PPM}	600	W				
Peak pulse current with a 10/1000 μ s waveform ⁽¹⁾	I _{PPM}	See next table	A				
Peak forward surge current 8.3 ms single half sine-wave uni-directional only $^{(2)}$	I _{FSM}	100	А				
Operating junction and storage temperature range	T _J , T _{STG}	- 55 to + 150	°C				

Notes

⁽¹⁾ Non-repetitive current pulse, per fig. 3 and derated above $T_A = 25$ °C per fig. 2.

⁽²⁾ Mounted on 0.2" x 0.2" (5.0 mm x 5.0 mm) copper pads to each terminal

Revision: 10-Dec-12

1

Document Number: 88392

For technical questions within your region: <u>DiodesAmericas@vishay.com</u>, <u>DiodesAsia@vishay.com</u>, <u>DiodesEurope@vishay.com</u> THIS DOCUMENT IS SUBJECT TO CHANGE WITHOUT NOTICE. THE PRODUCTS DESCRIBED HEREIN AND THIS DOCUMENT ARE SUBJECT TO SPECIFIC DISCLAIMERS, SET FORTH AT <u>www.vishay.com/doc?91000</u>



SMBJ5.0A thru SMBJ188A



www.vishay.com

Vishay General Semiconductor

ELECTRICAL CHARACTERISTICS (T _A = 25 °C unless otherwise noted)									
DEVICE TYPE MODIFIED "J" BEND LEAD	DEVICE MARKING CODE		BREAKDOWN VOLTAGE V _{BR} AT I _T ⁽¹⁾ (V)		TEST CURRENT I _T (mA)	STAND-OFF VOLTAGE V _{WM} (V)	MAXIMUM REVERSE LEAKAGE AT V _{WM}	MAXIMUM PEAK PULSE SURGE CURRENT	MAXIMUM CLAMPING VOLTAGE AT I _{PPM}
	UNI	BI	MIN.	MAX.	(11/2)		Ι _D (μΑ) ⁽³⁾	I _{РРМ} (А) ⁽²⁾	V _c (V)
(+)SMBJ5.0A (5)	KE	KE	6.40	7.07	10	5.0	800	65.2	9.2
⁽⁺⁾ SMBJ6.0A	KG	KG	6.67	7.37	10	6.0	800	58.3	10.3
⁽⁺⁾ SMBJ6.5A	KK	AK	7.22	7.98	10	6.5	500	53.6	11.2
⁽⁺⁾ SMBJ7.0A	KM	KM	7.78	8.60	10	7.0	200	50.0	12.0
⁽⁺⁾ SMBJ7.5A	KP	AP	8.33	9.21	1.0	7.5	100	46.5	12.9
⁽⁺⁾ SMBJ8.0A	KR	AR	8.89	9.83	1.0	8.0	50	44.1	13.6
(+)SMBJ8.5A	KT	AT	9.44	10.4	1.0	8.5	20	41.7	14.4
⁽⁺⁾ SMBJ9.0A	KV	AV	10.0	11.1	1.0	9.0	10	39.0	15.4
(+)SMBJ10A	KX	AX	11.1	12.3	1.0	10	5.0	35.3	17.0
⁽⁺⁾ SMBJ11A	KZ	KZ	12.2	13.5	1.0	11	5.0	33.0	18.2
⁽⁺⁾ SMBJ12A	LE	BE	13.3	14.7	1.0	12	5.0	30.2	19.9
⁽⁺⁾ SMBJ13A	LG	LG	14.4	15.9	1.0	13	1.0	27.9	21.5
⁽⁺⁾ SMBJ14A	LK	BK	15.6	17.2	1.0	14	1.0	25.9	23.2
⁽⁺⁾ SMBJ15A	LM	BM	16.7	18.5	1.0	15	1.0	24.6	24.4
⁽⁺⁾ SMBJ16A	LP	LM	17.8	19.7	1.0	16	1.0	23.1	26.0
(+)SMBJ17A	LR	LR	18.9	20.9	1.0	17	1.0	21.7	27.6
⁽⁺⁾ SMBJ18A	LT	BT	20.0	22.1	1.0	18	1.0	20.5	29.2
(+)SMBJ20A	LV	LV	22.2	24.5	1.0	20	1.0	18.5	32.4
(+)SMBJ22A	LX	BX	24.4	26.9	1.0	22	1.0	16.9	35.5
(+)SMBJ24A	LZ	BZ	26.7	29.5	1.0	24	1.0	15.4	38.9
(+)SMBJ26A	ME	CE	28.9	31.9	1.0	26	1.0	14.3	42.1
(+)SMBJ28A	MG	MG	31.1	34.4	1.0	28	1.0	13.2	45.4
(+)SMBJ30A	MK	CK	33.3	36.8	1.0	30	1.0	12.4	48.4
(+)SMBJ33A	MM	CM	36.7	40.6	1.0	33	1.0	11.3	53.3
(+)SMBJ36A	MP	CP	40.0	44.2	1.0	36	1.0	10.3	58.1
(+)SMBJ40A	MR	CR	44.4	49.1	1.0	40	1.0	9.3	64.5
(+)SMBJ43A	MT	CT	47.8	52.8	1.0	43	1.0	8.6	69.4
(+)SMBJ45A	MV	MV	50.0	55.3	1.0	45	1.0	8.3	72.7
(+)SMBJ48A	MX	MX	53.3	58.9	1.0	48	1.0	7.8	77.4
(+)SMBJ51A	MZ	MZ	56.7	62.7	1.0	51	1.0	7.3	82.4
(+)SMBJ54A	NE	NE	60.0	66.3	1.0	54	1.0	6.9	87.1
(+)SMBJ58A	NG	NG	64.4	71.2	1.0	58	1.0	6.4	93.6
(+)SMBJ60A	NK	NK	66.7	73.7	1.0	60	1.0	6.2	96.8
(+)SMBJ64A	NM	NM	71.1	78.6	1.0	64	1.0	5.8	103
(+)SMBJ70A	NP	NP	77.8	86.0	1.0	70	1.0	5.3	113
(+)SMBJ75A	NR	NR	83.3	92.1	1.0	75	1.0	5.0	121
(+)SMBJ78A	NT	NT	86.7	95.8	1.0	78	1.0	4.8	126
⁽⁺⁾ SMBJ85A	NV	NV	94.4	104	1.0	85	1.0	4.4	137
(+)SMBJ90A	NX	NX	100	111	1.0	90	1.0	4.1	146
(+)SMBJ100A	NZ	NZ	111	123	1.0	100	1.0	3.7	162
(+)SMBJ110A	PE	PE	122	135	1.0	110	1.0	3.4	177
(+)SMBJ120A	PG	PG	133	147	1.0	120	1.0	3.1	193
(+)SMBJ130A	PK	PK	144	159	1.0	130	1.0	2.9	209
(+)SMBJ150A	PM	PM	167	185	1.0	150	1.0	2.5	243
(+)SMBJ160A	PP	PP	178	197	1.0	160	1.0	2.3	259
(+)SMBJ170A	PR	PR	189	209	1.0	170	1.0	2.2	275
SMBJ188A	PS	PS	209	231	1.0	188	1.0	2.0	328

Notes

⁽¹⁾ Pulse test: $t_p \le 50 \text{ ms}$

 $^{(2)}\,$ Surge current waveform per fig. 3 and derate per fig. 2

 $^{(3)}$ For bi-directional types having V_{WM} of 10 V and less, the I_D limit is doubled

⁽⁴⁾ All terms and symbols are consistent with ANSI/IEEE C62.35

 $^{(5)}$ For the bi-directional SMBG/SMBJ5.8CA, the maximum V_{BR} is 7.25 V

⁽⁶⁾ $V_F = 3.5 \text{ V}$ at $I_F = 50 \text{ A}$ (uni-directional only)

(+) Underwriters laboratory recognition for the classification of protectors (QVGQ2) under the UL standard for safety 497B and file number E136766 for both uni-directional and bi-directional devices

Revision: 10-Dec-12

2

Document Number: 88392

For technical questions within your region: <u>DiodesAmericas@vishay.com</u>, <u>DiodesAsia@vishay.com</u>, <u>DiodesEurope@vishay.com</u> THIS DOCUMENT IS SUBJECT TO CHANGE WITHOUT NOTICE. THE PRODUCTS DESCRIBED HEREIN AND THIS DOCUMENT ARE SUBJECT TO SPECIFIC DISCLAIMERS, SET FORTH AT <u>www.vishay.com/doc?91000</u>



Vishay General Semiconductor

THERMAL CHARACTERISTICS ($T_A = 25$ °C unless otherwise noted)						
PARAMETER	SYMBOL	VALUE	UNIT			
Typical thermal resistance, junction to ambient ⁽¹⁾	$R_{ ext{ heta}JA}$	100	°C/W			
Typical thermal resistance, junction to lead	$R_{ ext{ heta}JL}$	20	C/ W			

Note

⁽¹⁾ Mounted on minimum recommended pad layout

ORDERING INFORMATION (Example)							
PREFERRED P/N	UNIT WEIGHT (g)	PREFERRED PACKAGE CODE	BASE QUANTITY	DELIVERY MODE			
SMBJ5.0A-E3/52	0.096	52	750	7" diameter plastic tape and reel			
SMBJ5.0A-E3/5B	0.096	5B	3200	13" diameter plastic tape and reel			
SMBJ5.0AHE3/52 (1)	0.096	52	750	7" diameter plastic tape and reel			
SMBJ5.0AHE3/5B (1)	0.096	5B	3200	13" diameter plastic tape and reel			

Note

(1) AEC-Q101 qualified

RATINGS AND CHARACTERISTICS CURVES (T_A = 25 °C unless otherwise noted)

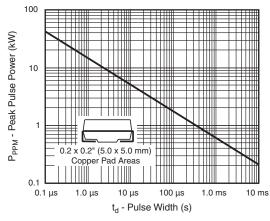


Fig. 1 - Peak Pulse Power Rating Curve

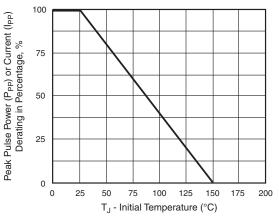
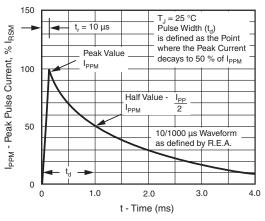
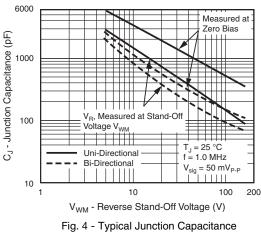


Fig. 2 - Pulse Power or Current vs. Initial Junction Temperature







Revision: 10-Dec-12

3

Document Number: 88392

For technical questions within your region: DiodesAmericas@vishay.com, DiodesAsia@vishay.com, DiodesEurope@vishay.com THIS DOCUMENT IS SUBJECT TO CHANGE WITHOUT NOTICE. THE PRODUCTS DESCRIBED HEREIN AND THIS DOCUMENT ARE SUBJECT TO SPECIFIC DISCLAIMERS, SET FORTH AT www.vishay.com/doc?91000



SMBJ5.0A thru SMBJ188A

Vishay General Semiconductor

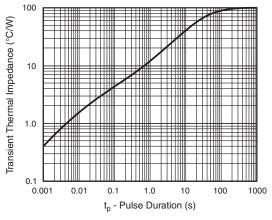


Fig. 5 - Typical Transient Thermal Impedance

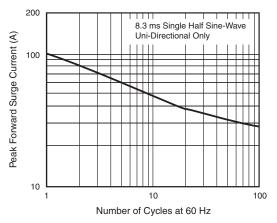
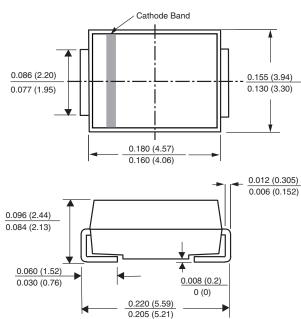


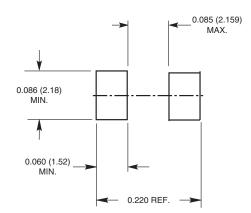
Fig. 6 - Maximum Non-Repetitive Peak Forward Surge Current

PACKAGE OUTLINE DIMENSIONS in inches (millimeters)



DO-214AA (SMB-J-Bend)

Mounting Pad Layout





Vishay

Disclaimer

ALL PRODUCT, PRODUCT SPECIFICATIONS AND DATA ARE SUBJECT TO CHANGE WITHOUT NOTICE TO IMPROVE RELIABILITY, FUNCTION OR DESIGN OR OTHERWISE.

Vishay Intertechnology, Inc., its affiliates, agents, and employees, and all persons acting on its or their behalf (collectively, "Vishay"), disclaim any and all liability for any errors, inaccuracies or incompleteness contained in any datasheet or in any other disclosure relating to any product.

Vishay makes no warranty, representation or guarantee regarding the suitability of the products for any particular purpose or the continuing production of any product. To the maximum extent permitted by applicable law, Vishay disclaims (i) any and all liability arising out of the application or use of any product, (ii) any and all liability, including without limitation special, consequential or incidental damages, and (iii) any and all implied warranties, including warranties of fitness for particular purpose, non-infringement and merchantability.

Statements regarding the suitability of products for certain types of applications are based on Vishay's knowledge of typical requirements that are often placed on Vishay products in generic applications. Such statements are not binding statements about the suitability of products for a particular application. It is the customer's responsibility to validate that a particular product with the properties described in the product specification is suitable for use in a particular application. Parameters provided in datasheets and/or specifications may vary in different applications and performance may vary over time. All operating parameters, including typical parameters, must be validated for each customer application by the customer's technical experts. Product specifications do not expand or otherwise modify Vishay's terms and conditions of purchase, including but not limited to the warranty expressed therein.

Except as expressly indicated in writing, Vishay products are not designed for use in medical, life-saving, or life-sustaining applications or for any other application in which the failure of the Vishay product could result in personal injury or death. Customers using or selling Vishay products not expressly indicated for use in such applications do so at their own risk. Please contact authorized Vishay personnel to obtain written terms and conditions regarding products designed for such applications.

No license, express or implied, by estoppel or otherwise, to any intellectual property rights is granted by this document or by any conduct of Vishay. Product names and markings noted herein may be trademarks of their respective owners.

Material Category Policy

Vishay Intertechnology, Inc. hereby certifies that all its products that are identified as RoHS-Compliant fulfill the definitions and restrictions defined under Directive 2011/65/EU of The European Parliament and of the Council of June 8, 2011 on the restriction of the use of certain hazardous substances in electrical and electronic equipment (EEE) - recast, unless otherwise specified as non-compliant.

Please note that some Vishay documentation may still make reference to RoHS Directive 2002/95/EC. We confirm that all the products identified as being compliant to Directive 2002/95/EC conform to Directive 2011/65/EU.

Vishay Intertechnology, Inc. hereby certifies that all its products that are identified as Halogen-Free follow Halogen-Free requirements as per JEDEC JS709A standards. Please note that some Vishay documentation may still make reference to the IEC 61249-2-21 definition. We confirm that all the products identified as being compliant to IEC 61249-2-21 conform to JEDEC JS709A standards.